

SMAJ Plastic-Encapsulate Diodes

Super Fast Recovery Rectifier Diode

Features

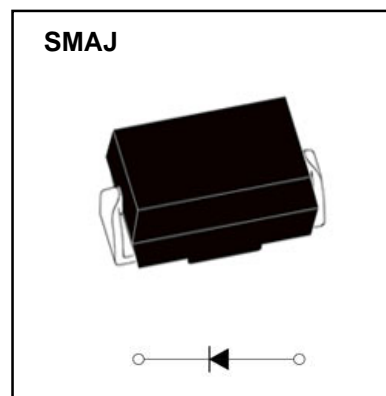
- I_o 1A
- VRRM 50V-600V
- High surge current capability
- Glass passivated chip
- Polarity: Color band denotes cathode

Applications

- Rectifier

Marking

- ER1X
X : From A To J



Limiting Values (Absolute Maximum Rating)

| Item | Symbol | Unit | Test Conditions | ER1 | | | | | | | |
|--------------------------------------|-------------|------------------|--|------------|-----|-----|-----|-----|-----|-----|-----|
| | | | | A | B | C | D | E | G | H | J |
| Repetitive Peak Reverse Voltage | V_{RRM} | V | | 50 | 100 | 150 | 200 | 300 | 400 | 500 | 600 |
| Maximum RMS Voltage | V_{RMS} | V | | 35 | 70 | 105 | 140 | 210 | 280 | 350 | 420 |
| Average Forward Current | $I_{F(AV)}$ | A | 60HZ Half-sine wave, Resistance load, $T_a=75^\circ\text{C}$ | 1.0 | | | | | | | |
| Surge(Non-repetitive)Forward Current | I_{FSM} | A | 60Hz Half-sine wave ,1 cycle , $T_a=25^\circ\text{C}$ | 30 | | | | | | | |
| Junction Temperature | T_J | $^\circ\text{C}$ | | -55~+125 | | | | | | | |
| Storage Temperature | T_{STG} | $^\circ\text{C}$ | | -55 ~ +150 | | | | | | | |

Electrical Characteristics (T=25°C Unless otherwise specified)

| Item | Symbol | Unit | Test Condition | ER1 | | | | | | | |
|-------------------------------|------------------|--------------------|--|-------------------------|---|---|------------------|------|---|------|---|
| | | | | A | B | C | D | E | G | H | J |
| Peak Forward Voltage | V_F | V | $I_F=1.0A$ | 0.95 | | | | 1.25 | | 1.70 | |
| Maximum reverse recovery time | t_{rr} | ns | $I_F=0.5A, I_R=1.0A, I_{rr}=0.25A$ | 35 | | | | | | | |
| Peak Reverse Current | I_{RRM1} | μA | $V_{RM}=V_{RRM}$ | $T_a=25^\circ\text{C}$ | | | | 5 | | | |
| | I | | | $T_a=100^\circ\text{C}$ | | | | 100 | | | |
| Thermal Resistance(Typical) | $R_{\theta J-A}$ | $^\circ\text{C/W}$ | Between junction and ambient | | | | 55 ¹⁾ | | | | |
| | $R_{\theta J-L}$ | | Between junction and terminal | | | | 25 ¹⁾ | | | | |
| Typical junction capacitance | C_j | pF | Measured at 1MHZ and Applied Reverse Voltage of 4.0 V.D.C. | | | | 15 | | | | |

Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

Typical Characteristics

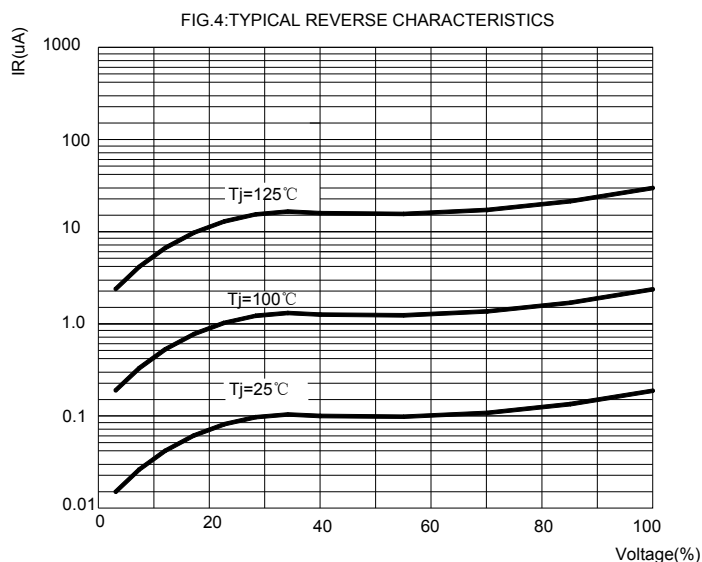
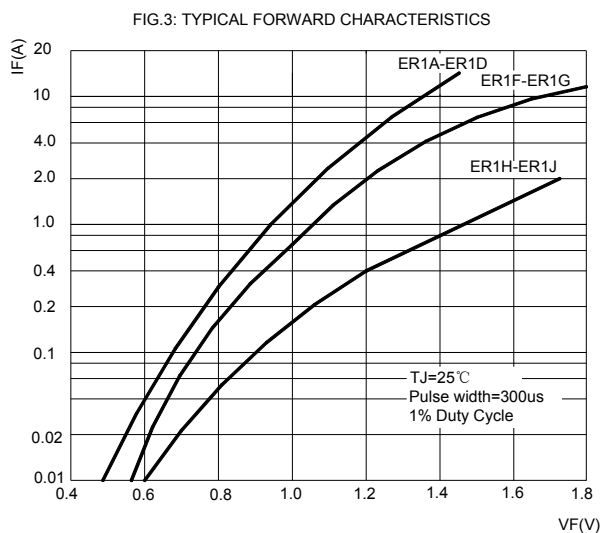
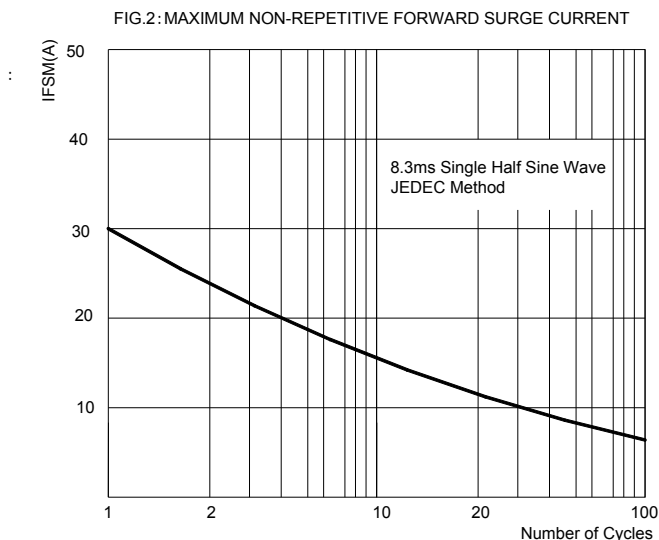
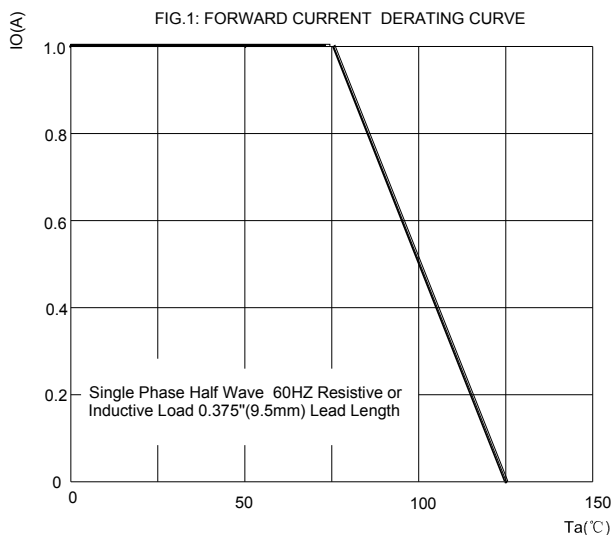
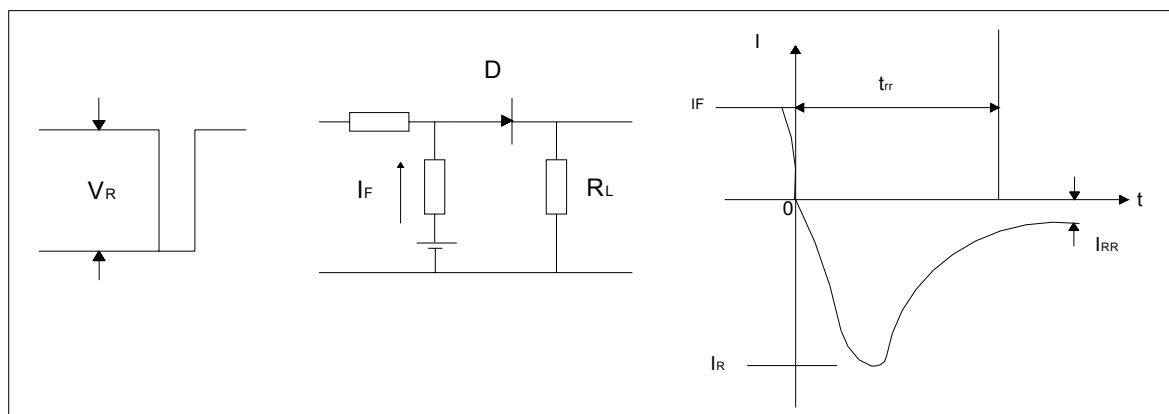
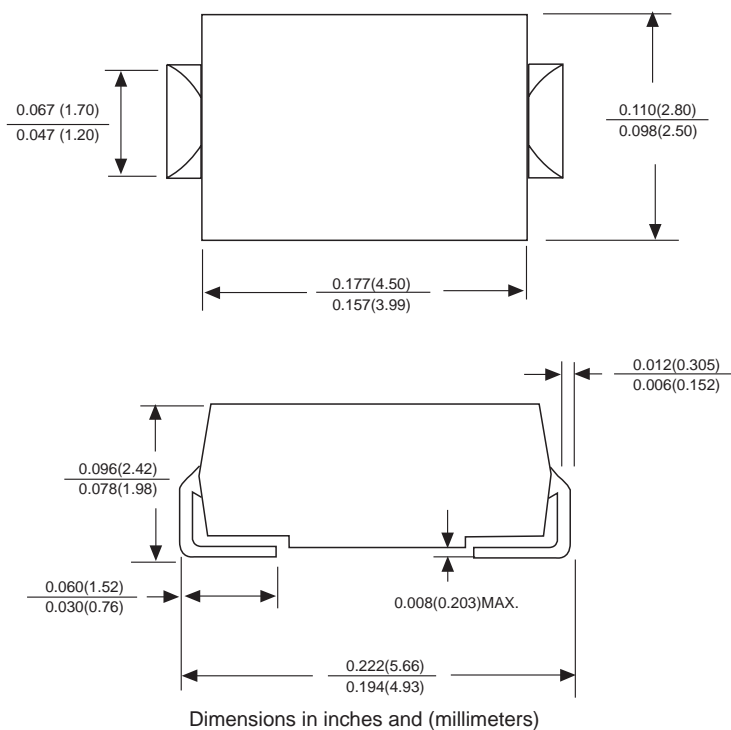


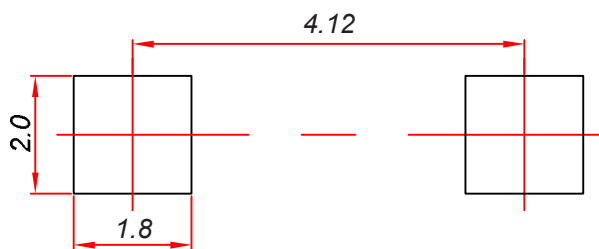
FIG.5: Diagram of circuit and Testing wave form of reverse recovery time



SMAJ Package Outline Dimensions



SMAJ Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

NOTICE

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Reel Taping Specifications For Surface Mount Devices-SMA

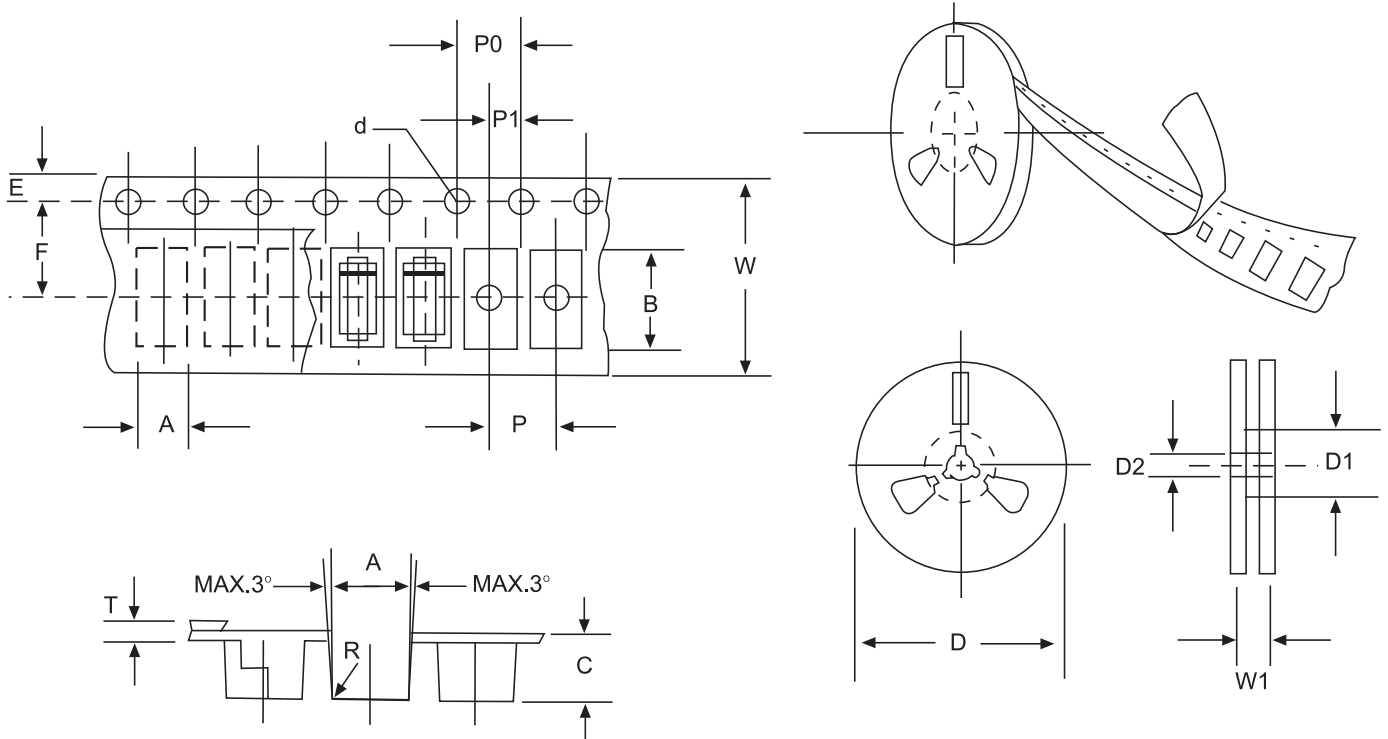


FIG:CONFIGURATION OF AXIAL TAPING

| ITEM | SYMBOL | SMA mm(inch) |
|------------------------|--------|--------------------------|
| Carrier width | A | 2.79±0.1(0.110±0.004) |
| Carrier length | B | 5.33±0.1(0.210±0.004) |
| Carrier depth | C | 2.36±0.1(0.093±0.004) |
| Sprocket hole | d | 1.5±0.05(0.059±0.0002) |
| Reel outside diameter | D | 330/178±2.0(13/7.0±0.79) |
| Reel inner diameter | D1 | 8.0±0.2(0.315±0.008) |
| Feed hole diameter | D2 | 13±0.5(0.512±0.020) |
| Sprocket hole position | E | 1.75±0.1(0.069±0.004) |
| Punch hole position | F | 5.5±0.05(0.217±0.002) |
| Punch hole pitch | P | 4.0±0.1(0.157±0.004) |
| Sprocket hole pitch | P0 | 4.0±0.1(0.157±0.004) |
| Embossment center | P1 | 2.0±0.1(0.079±0.004) |
| Total tape thickness | T | 0.28±0.02(0.011±0.0008) |
| Tape width | W | 12.0±0.2(0.472±0.008) |
| Reel width | W1 | 16.8±2.0(0.661±0.079) |

NOTE:Devices are packde in accordance with EIA standard RS-481-A and specification given above.